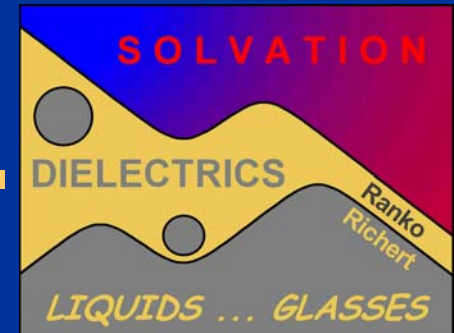


Hide-and-seek below the dc-conductivity signal

Ranko Richert



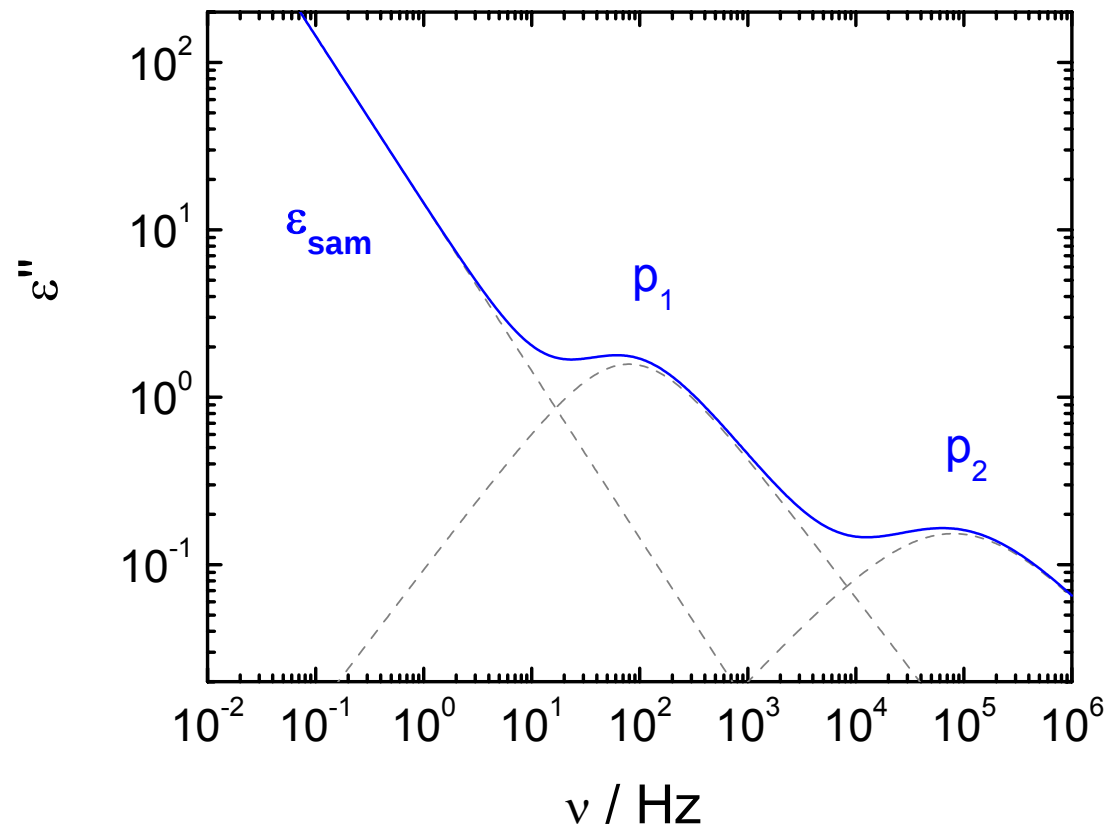
Roma, Dielectric Tutorial
30 August 2009

motivation

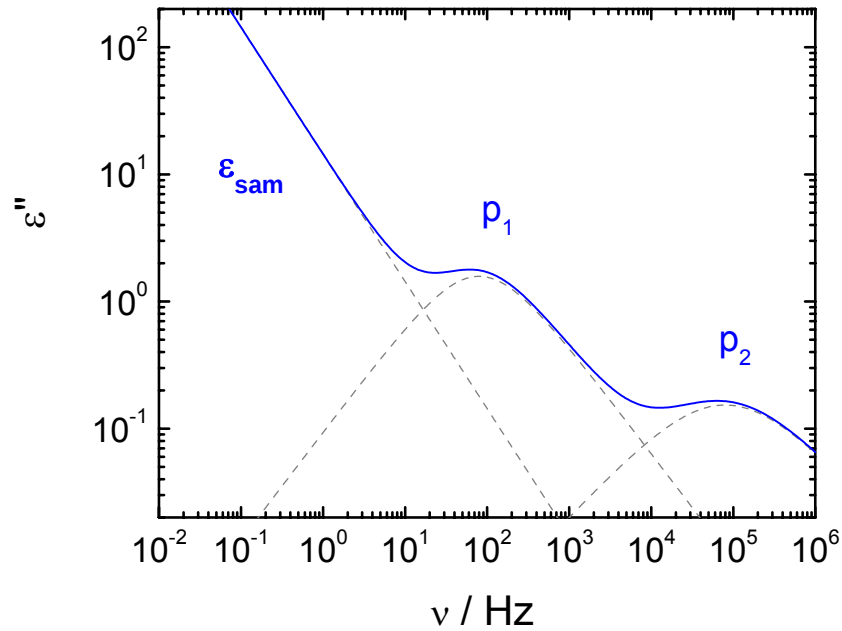
insulating electrodes

how much do we gain ?

motivation



all by synthetic data



$$\varepsilon_{\infty} = 2,$$

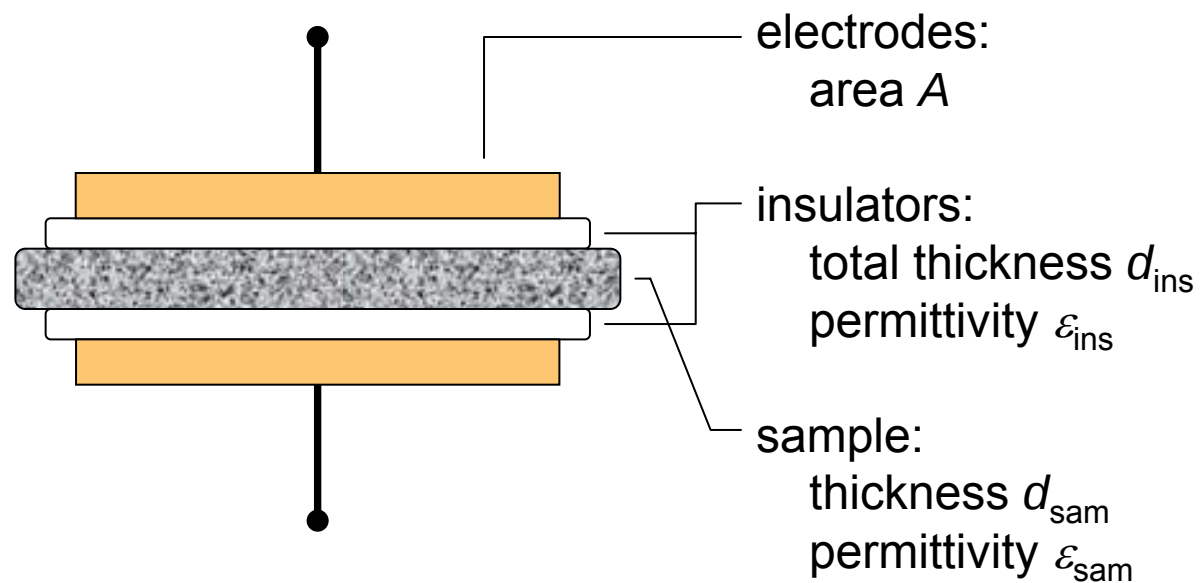
$$\alpha_1 = 0.85, \tau_1 = 2 \text{ ms}, \Delta\varepsilon_1 = 4,$$

$$\alpha_2 = 0.70, \tau_2 = 2 \mu\text{s}, \Delta\varepsilon_2 = 0.5,$$

$$\sigma_{\text{dc}} = 8 \times 10^{-12} \text{ S/cm}$$

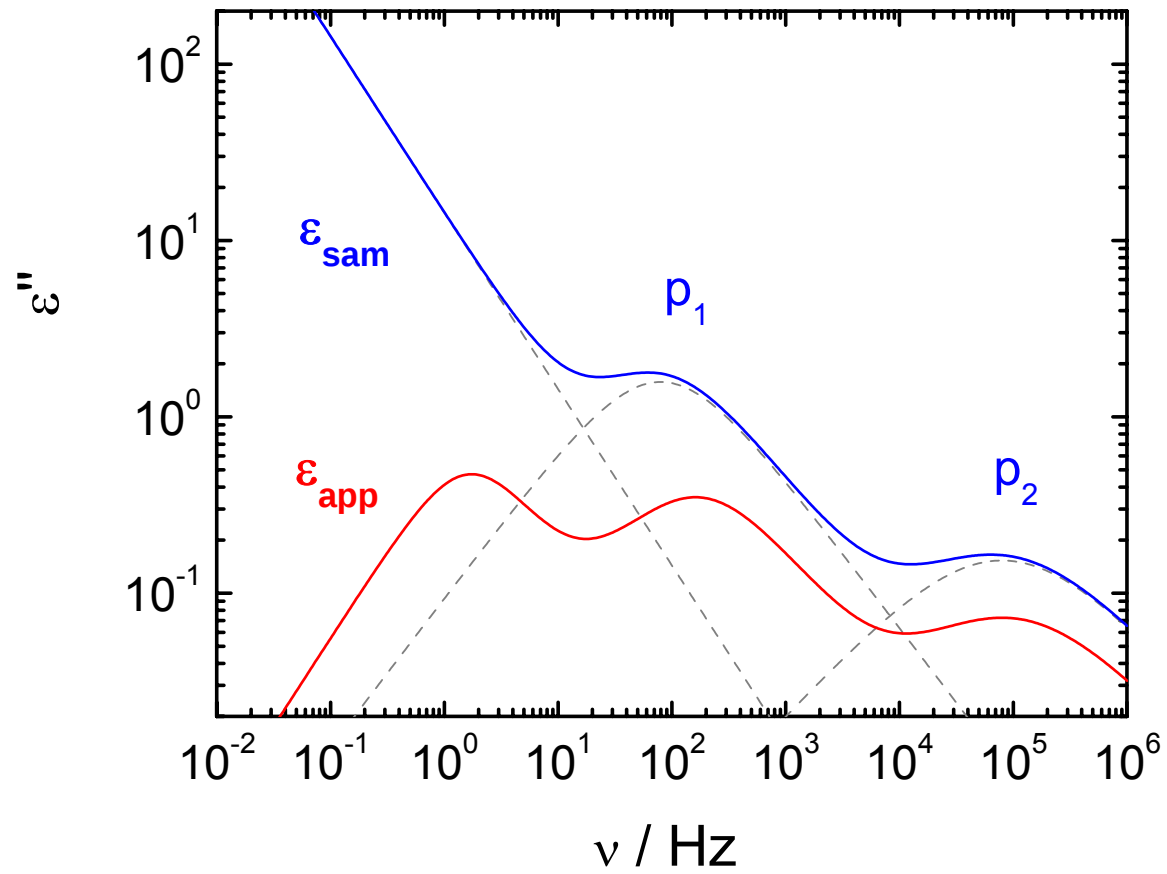
$$\varepsilon_{\text{sam}}^*(\omega) = \varepsilon_{\infty} + \frac{\Delta\varepsilon_1}{1 + (i\omega\tau_1)^{\alpha_1}} + \frac{\Delta\varepsilon_2}{1 + (i\omega\tau_2)^{\alpha_2}} + \frac{\sigma_{\text{dc}}}{\varepsilon_0 i \omega}$$

insulating the electrodes

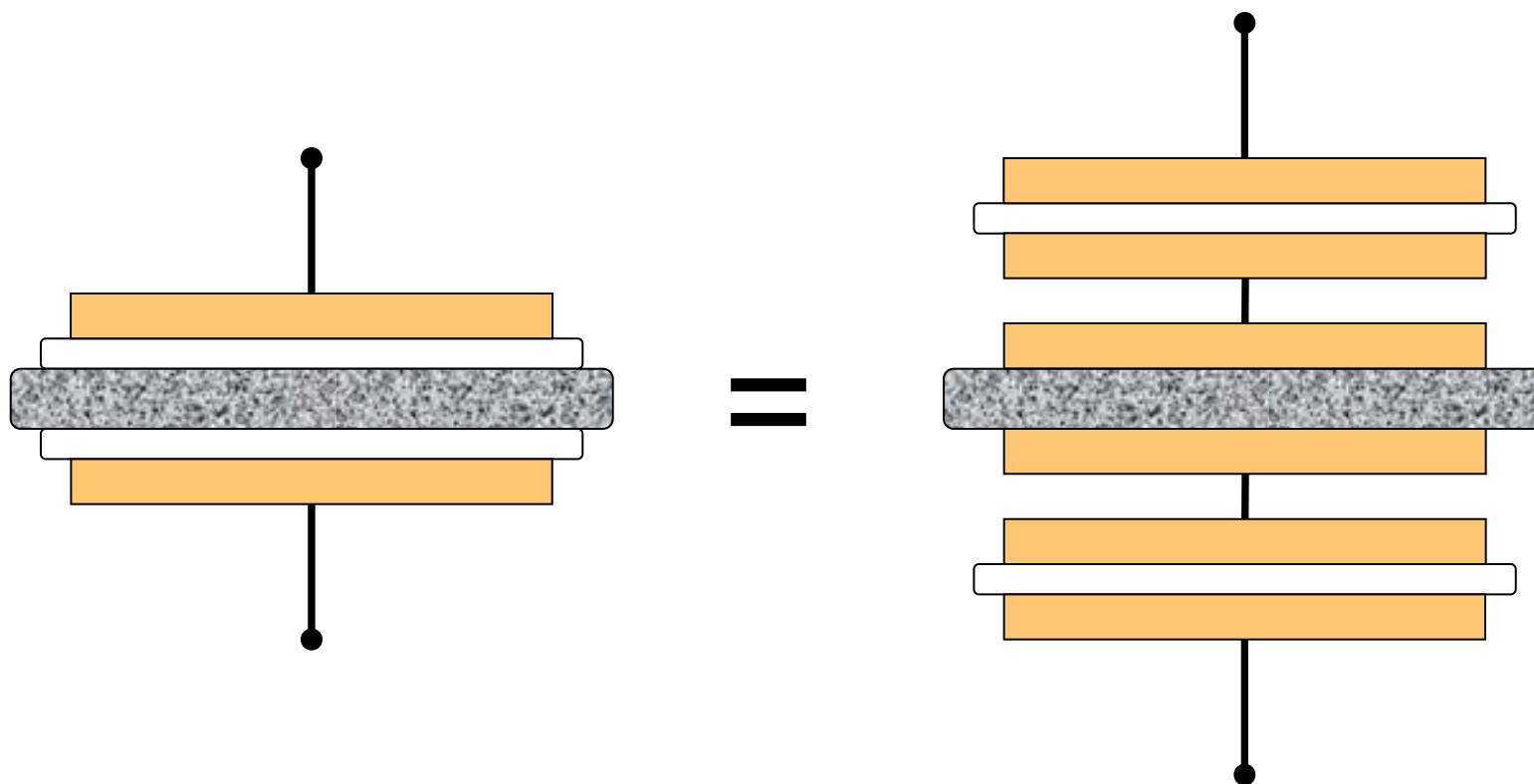


typical insulator: Teflon, PTFE (polytetrafluorethylene), $\epsilon_s = 2.04$

eureka ?



need to subtract the two 'Teflon-burgers'



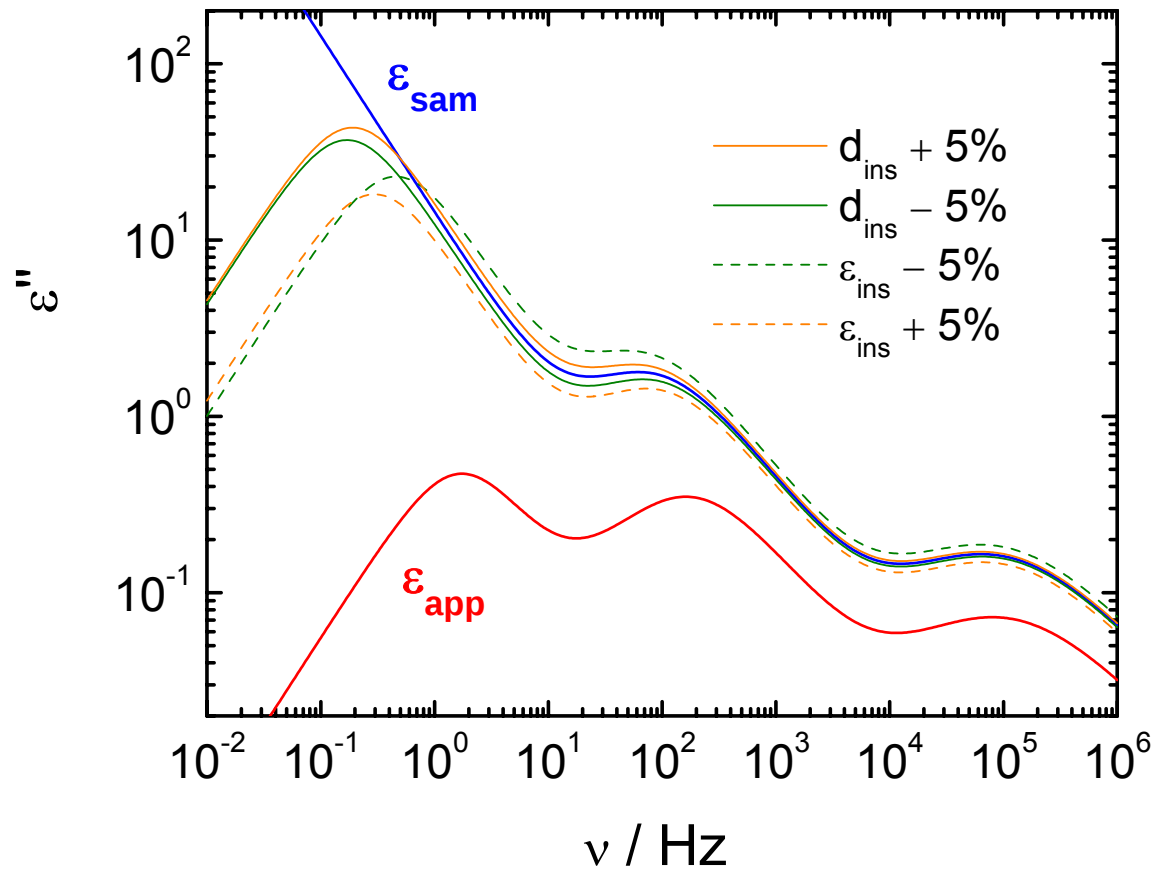
correction relations

$$Z_{app} = Z_{sam} + Z_{ins} \quad \text{with} \quad Z_x = \frac{1}{i\omega C_x} = \frac{d_x}{i\omega\epsilon_0\epsilon_x A}$$

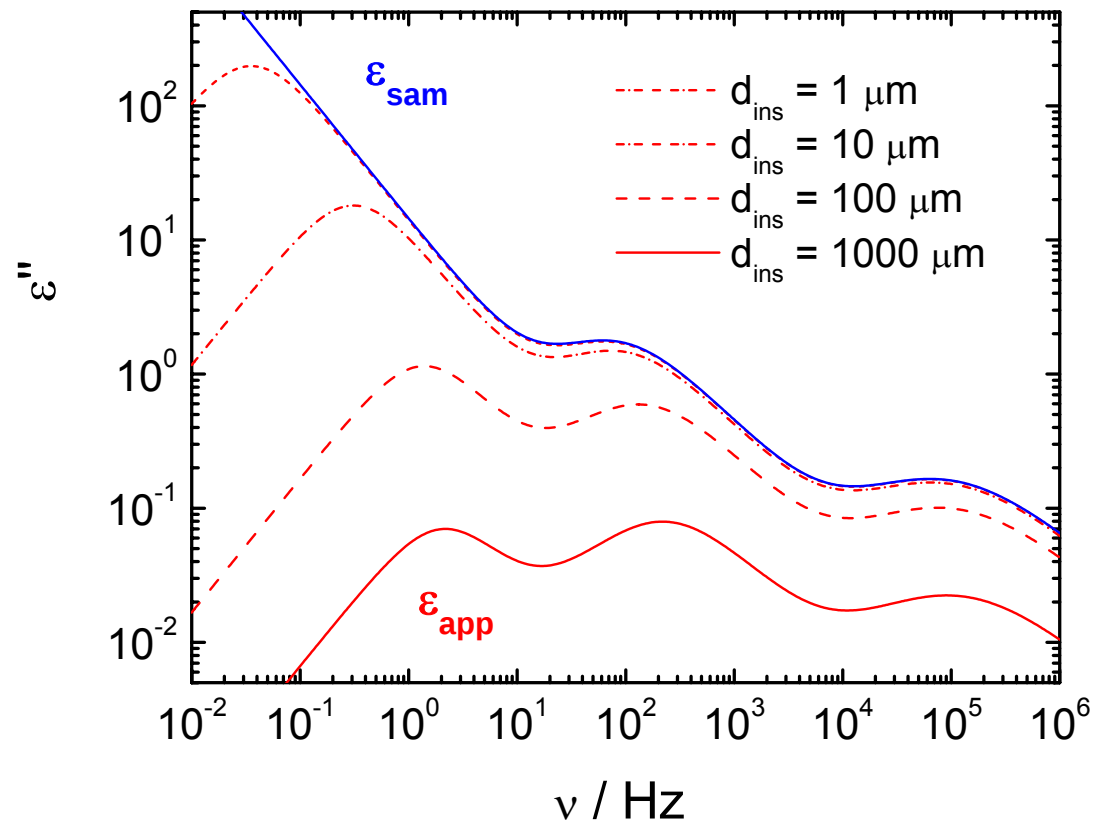
$$\epsilon_{app} = (d_{sam} + d_{ins}) \frac{\epsilon_{sam}\epsilon_{ins}}{d_{sam}\epsilon_{ins} + d_{ins}\epsilon_{sam}}$$

$$\epsilon_{sam} = d_{sam} \frac{\epsilon_{app}\epsilon_{ins}}{(d_{sam} + d_{ins})\epsilon_{ins} - d_{ins}\epsilon_{app}}$$

corrected data

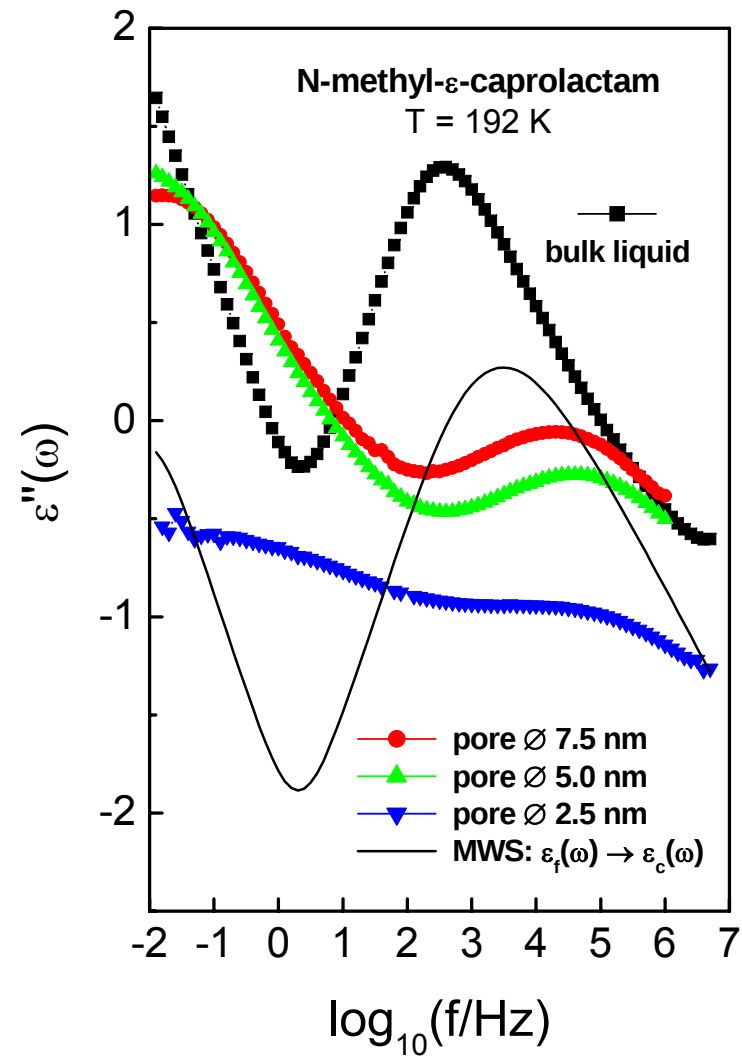
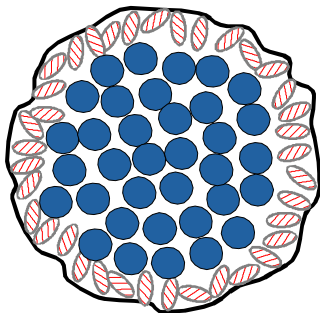


thickness is more relevant than insulating



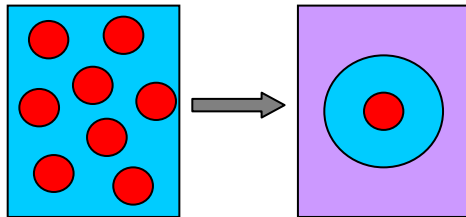
dielectric relaxation in porous glasses

nominal size	pore diameter	pore fraction	surface area
25 Å	26 Å	0.39	609 m ² /g
50 Å	46 Å	0.68	594 m ² /g
75 Å	84 Å	0.72	342 m ² /g



dielectric relaxation in porous glasses

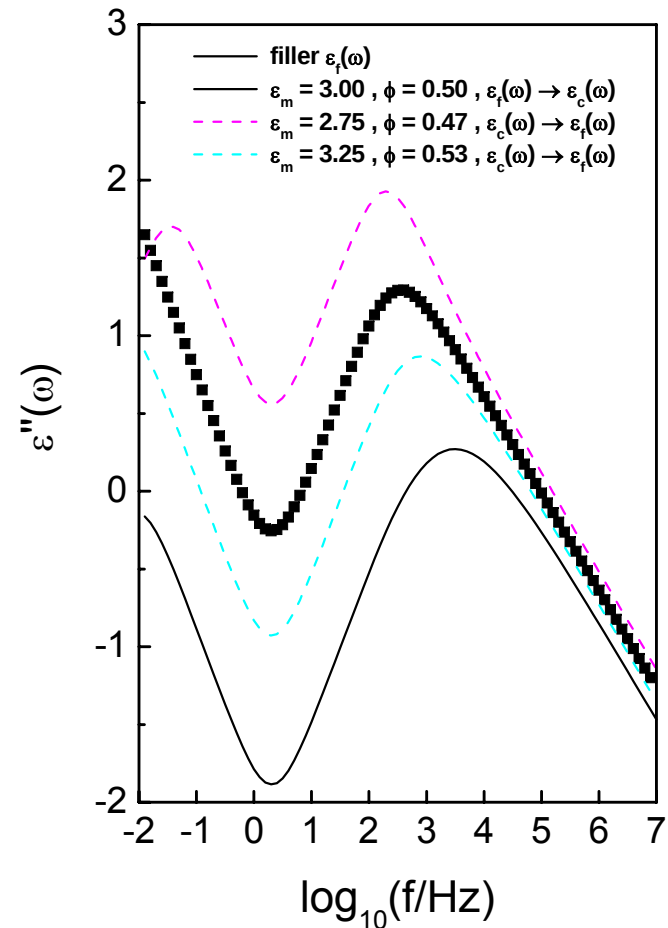
Maxwell-
Wagner-
Sillars



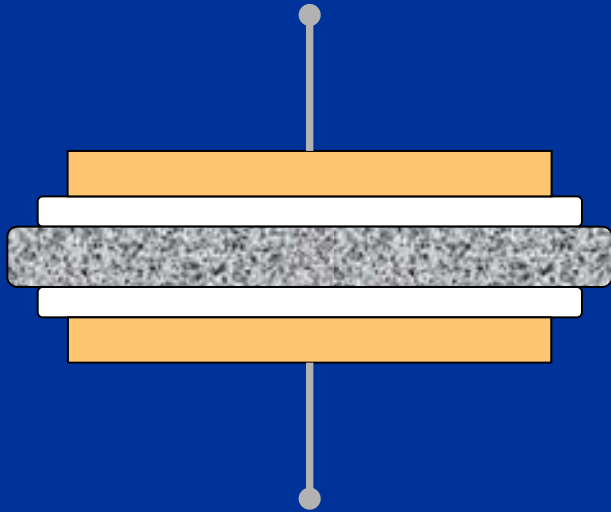
ϵ_f : filler
 ϵ_m : matrix
 ϵ_c : composite

$$\epsilon_c^*(\omega) = \epsilon_m^*(\omega) \cdot \frac{[n \cdot \epsilon_f^*(\omega) + (1-n) \cdot \epsilon_m^*(\omega)] + (1-n) \cdot [\epsilon_f^*(\omega) + \epsilon_m^*(\omega)] \cdot \varphi}{[n \cdot \epsilon_f^*(\omega) + (1-n) \cdot \epsilon_m^*(\omega)] - n \cdot [\epsilon_f^*(\omega) + \epsilon_m^*(\omega)] \cdot \varphi}$$

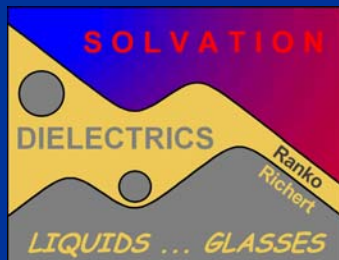
R.W. Sillars, J. Inst. Electr. Eng. 80 (1937) 378



CONCLUSIONS



- ➔ Insulation will not help finding peaks that are otherwise hidden under dc-conductivity signal.
- ➔ Because of the necessary correction, the only effect is to add errors.
- ➔ Simple reason: proximity of PTFE will not change properties of sample.
- ➔ Only use of insulating is to prevent additional charges being added, but noble metals usually do the same.



thanks to Christiane Alba-Simionesco
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